## Anomalous photovoltaic effect in LiNbO₃:Fe in polarized light

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Dependence of the photovoltaic current in the ferroelectric LiNbO<sub>3</sub>:Fe on the direction of light polarization is obtained for the first time, and the components of the photovoltaic tensor  $k_{ijk}$  are determined. The longitudinal, photorefractive effect is observed.

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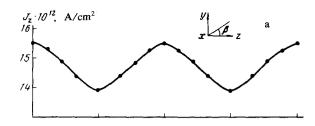
The anomalous photovoltaic effect (AP effect) in crystals without the symmetry center is described by the tensor of third order  $\alpha_{ijk}^{(1)}$ 

$$J_i = \alpha_{ijk} E_i E_k \,, \tag{1}$$

where  $J_i$  is the photovoltaic current, and  $E_j$  and  $E_k$  are projections of the light polarization vector (for linearly polarized light). The AP effect in ferroelectric materials was observed for the first time in Refs. 2 and 3 in LiNbO<sub>3</sub>:Fe and in barium and strontium niobate crystals. The dependence of  $J_z$  on the light polarization (z is the direction of spontaneous polarization) in ferroelectric materials was not observed in Refs. 2 and 3 or in the subsequent work,<sup>141</sup> and it was reported that  $J_y = J_x = 0$ . At the same time, the AP effect in a cubic piezoelectric Bi<sub>12</sub>SiO<sub>20</sub> was observed only in the polarized light.<sup>151</sup> In this paper, we report for the first time the dependence of the photovoltaic current on light polarization in LiNbO<sub>3</sub>:Fe, and we determine all the components of the photovoltaic tensor.

The measurements performed using an iron-doped lithium niobate single crystal in the shape of a parallelepiped with the (001), (010) and (100) faces and the corresponding linear dimensions  $0.5\times0.35\times0.1$  cm. The crystal was illuminated with a linearly polarized light at  $\lambda=500$  nm, which corresponds to the edge of absorption band of Fe<sup>2+</sup> in LiNbO<sub>3</sub>:Fe.<sup>161</sup> A xenon lamp and ZMR monochromator were used as a source of light. The method described earlier<sup>161</sup> was used for measuring both the steady-state photovoltaic current J and the field induced by it  $\widetilde{E}=J/\sigma$ , where  $\sigma$  is the photoconductivity. All the measurements were conducted at a constant light intensity  $I=2.3\times10^{-3}$  W/cm<sup>2</sup> at room temperature.

The photovoltaic current was measured both in the direction of spontaneous polarization (z axis) and in the x and y directions for all possible orientations of light polarization plane. Figures 1 a, b, and c show the experimental dependence of the photovoltaic current  $J_z$ ,  $J_y$ , and  $J_x$  on the angle  $\beta$  between the light polarization plane and the corresponding crystal axis. Allowing for the nontrivial value of the  $\alpha_{ijk}$  tensor component for the point group 3m to which lithium niobate belongs, we write the expressions, in accordance with Eq. (1), for the photovoltaic current  $J_z$ ,  $J_y$ , and  $J_x$ 



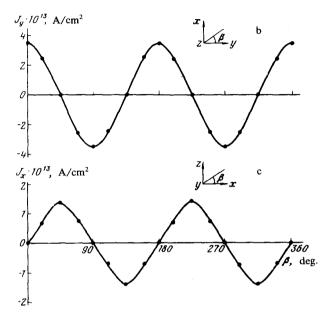


FIG. 1. Dependence of the photovoltaic currents  $J_x(a)$ ,  $J_y(b)$ , and  $J_x(c)$  on the orientation of the plane of the light polarization in LiNbO<sub>3</sub>:Fe. The direction of light propagation is indicated in the insets.

(the direction of propagation of the linearly polarized light is shown in Figs. 1a, b and c, respectively).

$$I_{z} = a_{31}I + (a_{33} - a_{3})I\cos^{2}\beta, \qquad (2)$$

$$I_{\gamma} = \alpha_{22} I (1 - \sin^2 \beta), \tag{3}$$

$$J_{x} = a_{15} l \sin 2\beta, \tag{4}$$

where I is the intensity of light. A comparison of the experimental orientational dependences in Figs. 1 a, b, and c, respectively, with Eqs. (2), (3), and (4) shows a good agreement. Although the currents  $J_x$  and  $J_y$  have nonzero values only for the polarized light and change their signs twice when the polarization plane is rotated by 360°, the current in the direction of spontaneous polarization has a component that is independent of the direction of the polarization of light. This possibly accounts for the fact that the effect of light polarization on the photovoltaic current  $J_z$  has not been observed earlier. Two interesting cases are not shown in Fig. 1. If the light propagates along the x axis, then  $J_x = 0$  for any value of  $\beta$ . When the light propagates along the z axis, the current  $J_z = \alpha_{33}I$  is independent of the direction of light polarization. We note that the amplitudes of the currents  $J_y$  and  $J_x$  are smaller than  $J_z$  by more than an

order of magnitude. Therefore, the induced field  $\tilde{E}_y$ ,  $\tilde{E}_x$  is by more than an order of magnitude lower than  $\tilde{E}_z$  and does not exceed 200 V/cm. However, these fields were sufficient to observe the longitudinal, photorefractive effect in the direction of the z axis,  $\delta(\Delta n) \approx 10^{-6}$ , which at the light intensity shown above was more than an order of magnitude lower than the transverse photorefractive effect (in the direction of the y axis) determined earlier. [6]

We determined from a comparison of the curves in Figs. 1 a, b, and c with Eqs. (2)–(4) the numerical values of  $\alpha_{ijk}$  or the photovoltaic coefficients  $k_{ijk} = 1/\alpha^* \alpha_{ijk}$ , where  $\alpha^*$  is the absorption coefficient (in LiNbO<sub>3</sub>:Fe  $\alpha^* \approx 4.5$  cm<sup>-1</sup> at  $\lambda = 500$  nm; pleochroism can be disregarded). The following values were obtained:  $k_{31} = 1.4 \times 10^{-9}$ ,  $k_{33} \approx 1.5 \times 10^{-9}$ ,  $k_{22} \approx 0.5 \times 10^{-10}$ , and  $k_{15} \approx 1.0 \times 10^{-11}$  A·cm/W. The values of  $k_{31}$  and  $k_{33}$  are close to the value of the photovoltaic coefficient obtained earlier for LiNbO<sub>3</sub>:Fe in unpolarized light.<sup>(7)</sup>

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